

IPC022N03L3X1SA1

IPC022N03L3X1SA1 Information

Heisener.com	IPC022N03L3X1SA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 30V SAWN BARE DIE Die For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPC022N03L3X1SA1 Specifications

Manufacturer Part Number	IPC022N03L3X1SA1	
Manufacturer	Infineon Technologies	
Category	Discrete Semiconductor Products	
	Transistors - FETs, MOSFETs - Single	
Package	Die	
Series	OptiMOS?	
FET Type	N-Channel	
Technology	MOSFET (Metal Oxide)	
Drain to Source Voltage (Vdss)	30V	
Current - Continuous Drain (Id) @ 25°C	1A (Tj)	
Drive Voltage (Max Rds On, Min Rds On)	10V	
Vgs(th) (Max) @ Id	2.2V @ 250µA	
Gate Charge (Qg) (Max) @ Vgs	-	
Input Capacitance (Ciss) (Max) @ Vds	-	
Vgs (Max)	-	
FET Feature	-	
Power Dissipation (Max)	-	
Rds On (Max) @ Id, Vgs	50 mOhm @ 2A, 10V	
Operating Temperature	-	
Mounting Type	Surface Mount	
Supplier Device Package	Sawn on foil	
Package / Case	Die	
	Report errors?	

IPC022N03L3X1SA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

IPC022N03L3X1SA1 Payment Methods



IPC022N03L3X1SA1 Shipping Methods



If you have any question about IPC022N03L3X1SA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com